

HIGHER INVARIANTS: TOPOLOGICAL INSULATORS

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Sponsoring



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Main References

M. KÖNIG, S. WIEDMANN, C. BRÜNE, A. ROTH, H. BUHMANN, L. W. MOLENKAMP, X. L. QI, S. C. ZHANG
Science, **318**, (2007), 766-770

D. HSIEH, D. QIAN, L. WRAY, Y. XIA, Y. S. HOR, R. J. CAVA, M. Z. HASAN, *Nature*, **452**, (2008), 970-975

M. Z. HAZAN, C. L. KANE, Topological Insulators, *Rev. Mod. Phys.*, **82**, (2010), 3045-3067

H. SCHULZ-BALDES, S. TEUFEL, *Comm. Math. Phys.*, **319**, (2013), 649-681

E. PRODAN, B. LEUNG, J. BELLISSARD, “The non-commutative n th-Chern number ($n \geq 1$)”, (*in preparation*), (2013)

Content

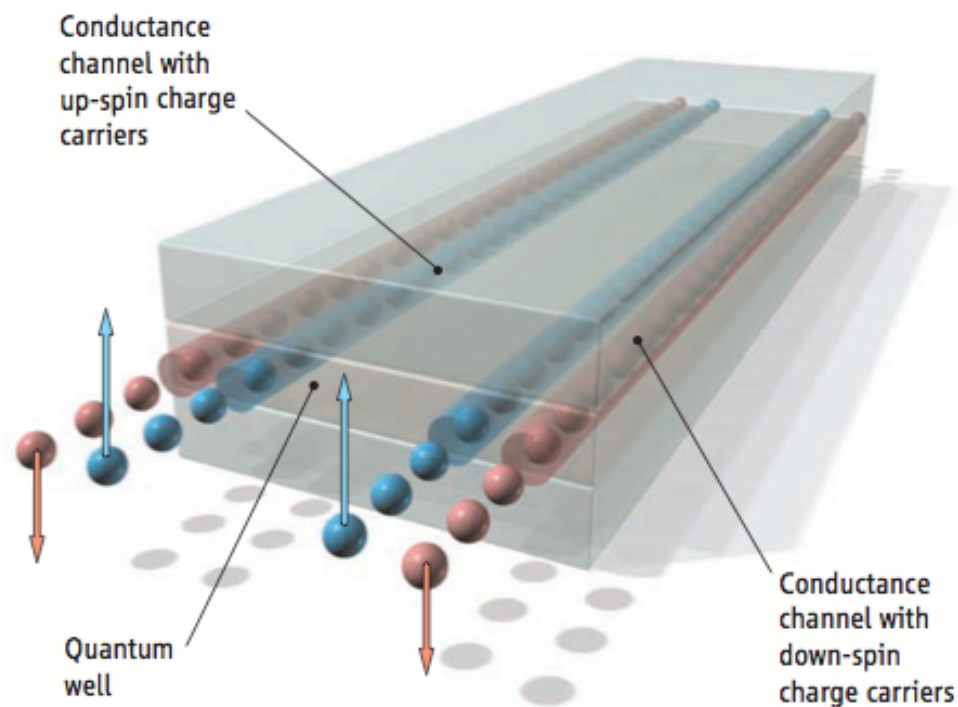
1. Topological Insulators
2. Semiconductors
3. The $\mathbb{Z}_2$ -Invariant
4. Magneto-Electric Response

I - TOPOLOGICAL INSULATORS

M. Z. HAZAN, C. L. KANE, Topological Insulators, *Rev. Mod. Phys.*, **82**, (2010), 3045-3067

Two Dimensional Compounds

M. KÖNIG, S. WIEDMANN, C. BRÜNE, A. ROTH, H. BUHMANN, L. W. MOLENKAMP, X. L. QI, S. C. ZHANG
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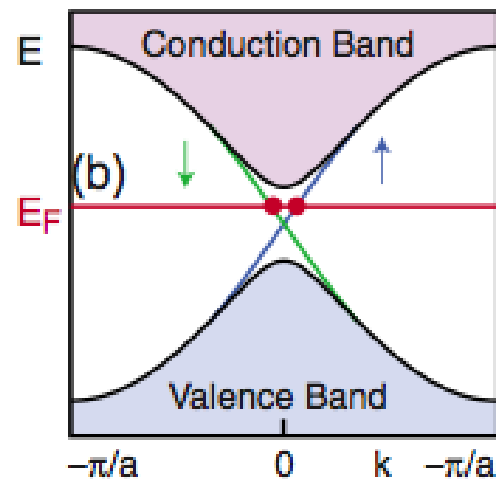
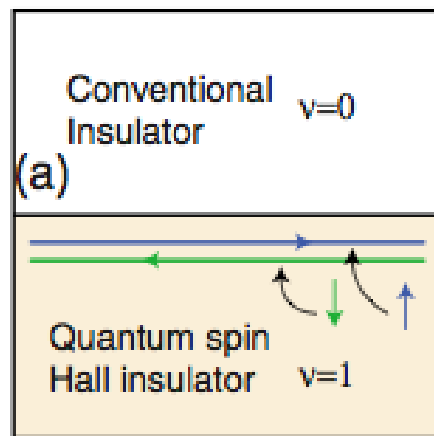


Schematic of the spin-polarized edge channels in a quantum spin Hall insulator.

2D- $HgTe$ semi-conductor with inverted band structure provide a way to create a spin polarized channel of electronic current, protected by topological invariant

Two Dimensional Compounds

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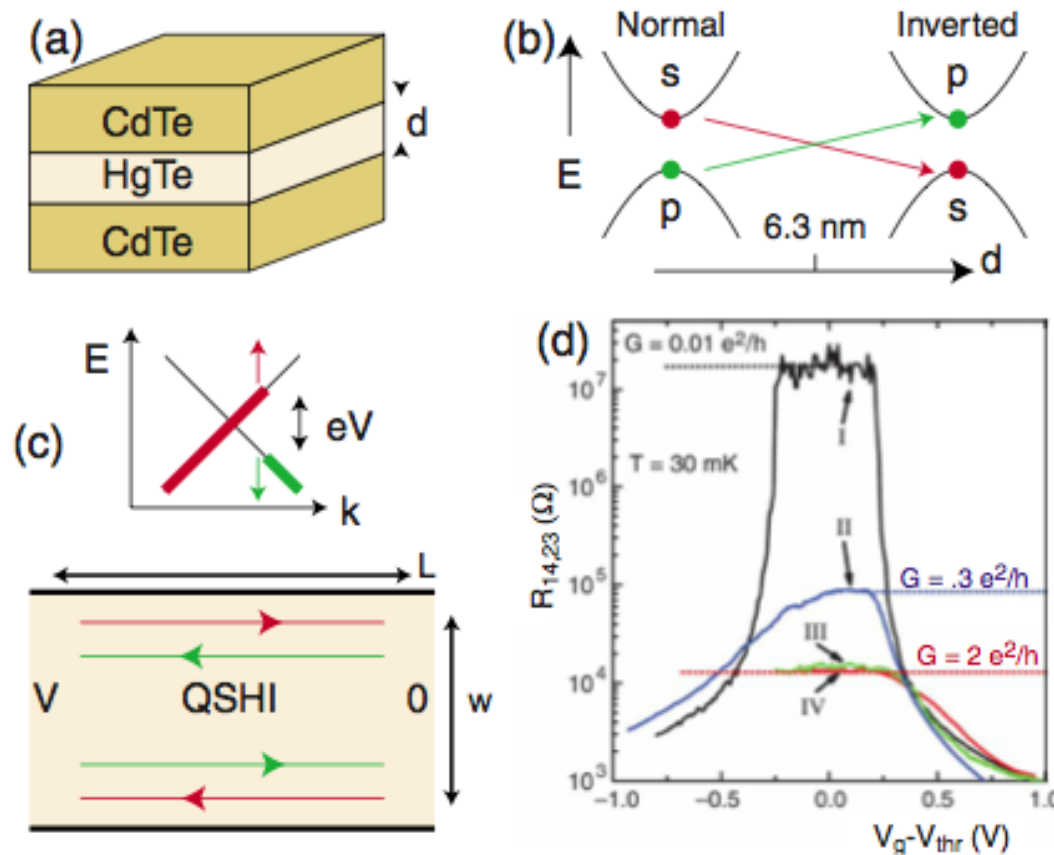


Edge states:
Right edge states
interpolating between
valence and conduction
bands
Colors show the spin

Slope = velocity

Two Dimensional Compounds

M. KÖNIG, S. WIEDMANN, C. BRÜNE, A. ROTH, H. BUHMANN, L. W. MOLENKAMP, X. L. QI, S. C. ZHANG
Science, **318**, (2007), 766-770



Edge states have
quantized conductance

Three Dimensional Compounds

D. HSIEH, D. QIAN, L. WRAY, Y. XIA, Y. S. HOR, R. J. CAVA & M. Z. HASAN,
Nature, **452**, (2008), 970-975

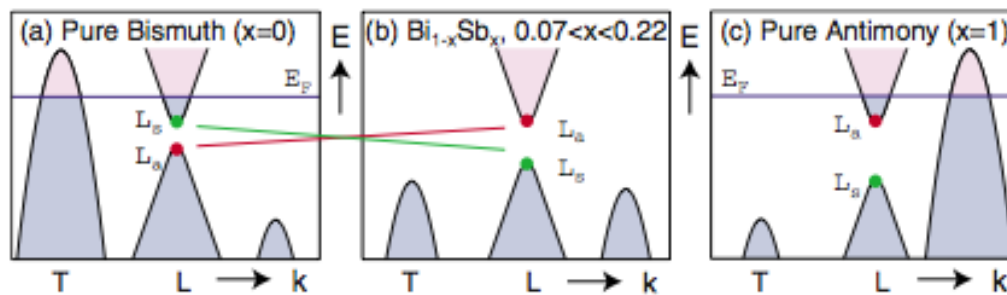
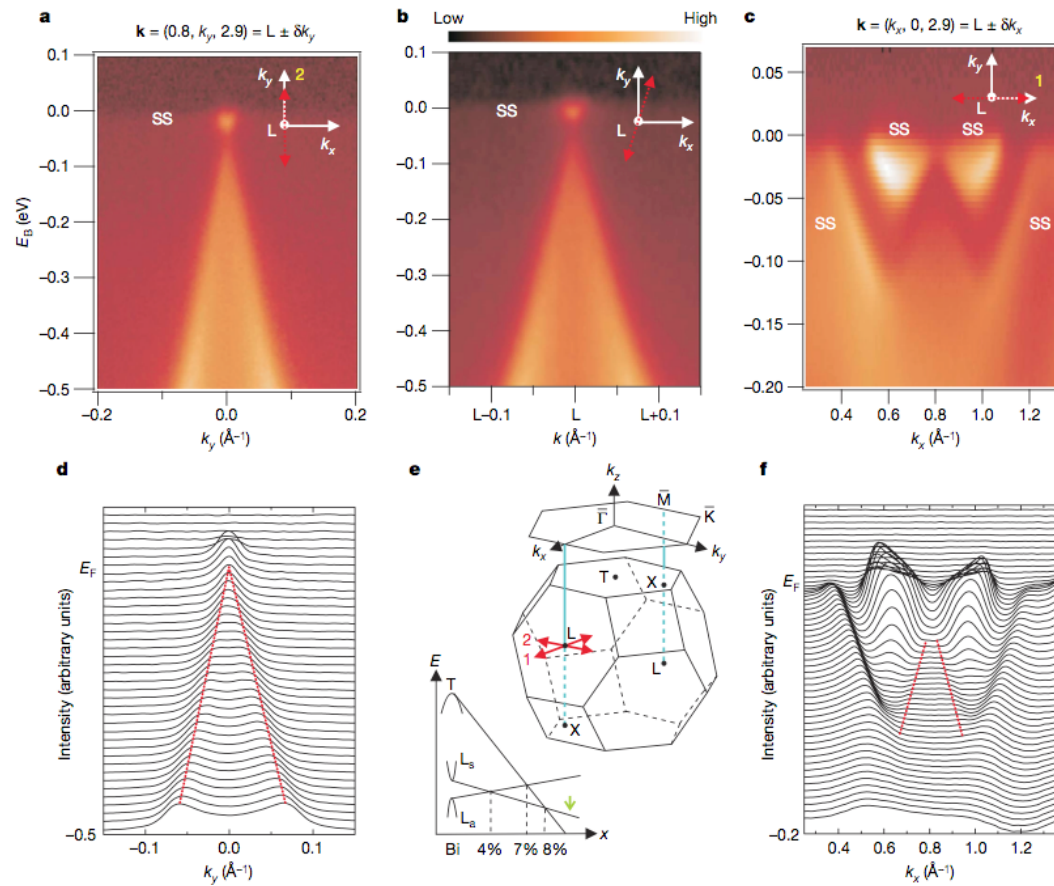


FIG. 8. (Color online) Schematic representation of the band structure of Bi_{1-x}Sb_x, which evolves from semimetallic behavior for $x < 0.07$ to semiconducting behavior for $0.07 < x < 0.22$ and back to semimetallic behavior for $x > 0.18$. The conduction and valence bands $L_{s,a}$ invert at $x \sim 0.04$.

3D-*Bi*_{0.9}*Sb*_{0.1}
Inverted band structure

Three Dimensional Compounds

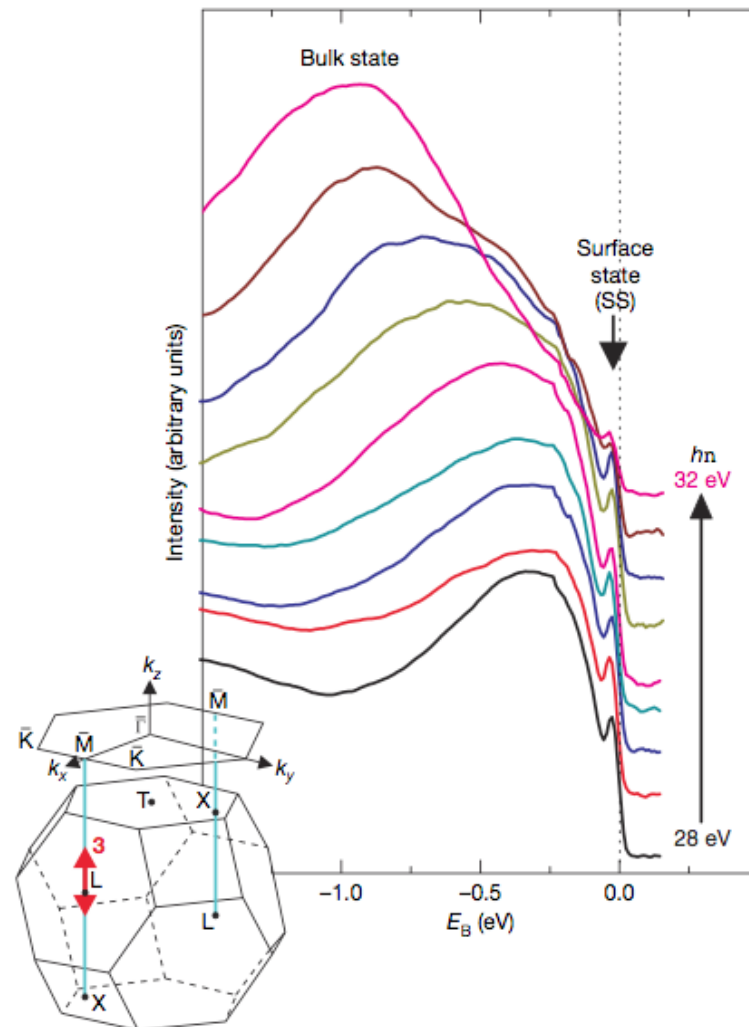
D. HSIEH, D. QIAN, L. WRAY, Y. XIA, Y. S. HOR, R. J. CAVA & M. Z. HASAN,
Nature, **452**, (2008), 970-975



3D- $\text{Bi}_{0.9}\text{Sb}_{0.1}$
 Dirac dispersion cone

Three Dimensional Compounds

D. HSIEH, D. QIAN, L. WRAY, Y. XIA, Y. S. HOR, R. J. CAVA & M. Z. HASAN,
Nature, **452**, (2008), 970-975



$3D\text{-}Bi_{0.9}Sb_{0.1}$
Surface states evidence

II - Semiconductors

N. W. ASHCROFT, N. D. MERMIN, *Solid State Physics*, Holt, Rinehart and Winston Eds., (1976)

B. I. SHKLOVSKII, A. L. EFROS, *Electronic Properties of Doped Semiconductors*, Springer, (1984).

The Columns II-VI

	3A	4A	5A	6A
	5 B $1s^2 2s^2 p^1$	6 C $1s^2 2s^2 p^2$	7 N $1s^2 2s^2 p^3$	8 O $1s^2 2s^2 p^4$
	13 Al $[\text{Ne}] 3s^2 p^1$	14 Si $[\text{Ne}] 3s^2 p^2$	15 P $[\text{Ne}] 3s^2 p^3$	16 S $[\text{Ne}] 3s^2 p^4$
2B	30 Zn $[\text{Ar}] 3d^{10} 4s^2$	31 Ga $[\text{Ar}] 3d^{10} 4s^2 p^1$	32 Ge $[\text{Ar}] 3d^{10} 4s^2 p^2$	33 As $[\text{Ar}] 3d^{10} 4s^2 p^3$
	48 Cd $[\text{Kr}] 4d^{10} 5s^2$	49 In $[\text{Kr}] 4d^{10} 5s^2 p^1$	50 Sn $[\text{Kr}] 4d^{10} 5s^2 p^2$	51 Sb $[\text{Kr}] 4d^{10} 5s^2 p^3$
	80 Hg $[\text{Xe}] 4f^{14} 5d^{10} 6s^2$	81 Tl $[\text{Xe}] 4f^{14} 5d^{10} 6s^2 p^1$	82 Pb $[\text{Xe}] 4f^{14} 5d^{10} 6s^2 p^2$	83 Bi $[\text{Xe}] 4f^{14} 5d^{10} 6s^2 p^3$
			84 Po $[\text{Xe}] 4f^{14} 5d^{10} 6s^2 p^4$	

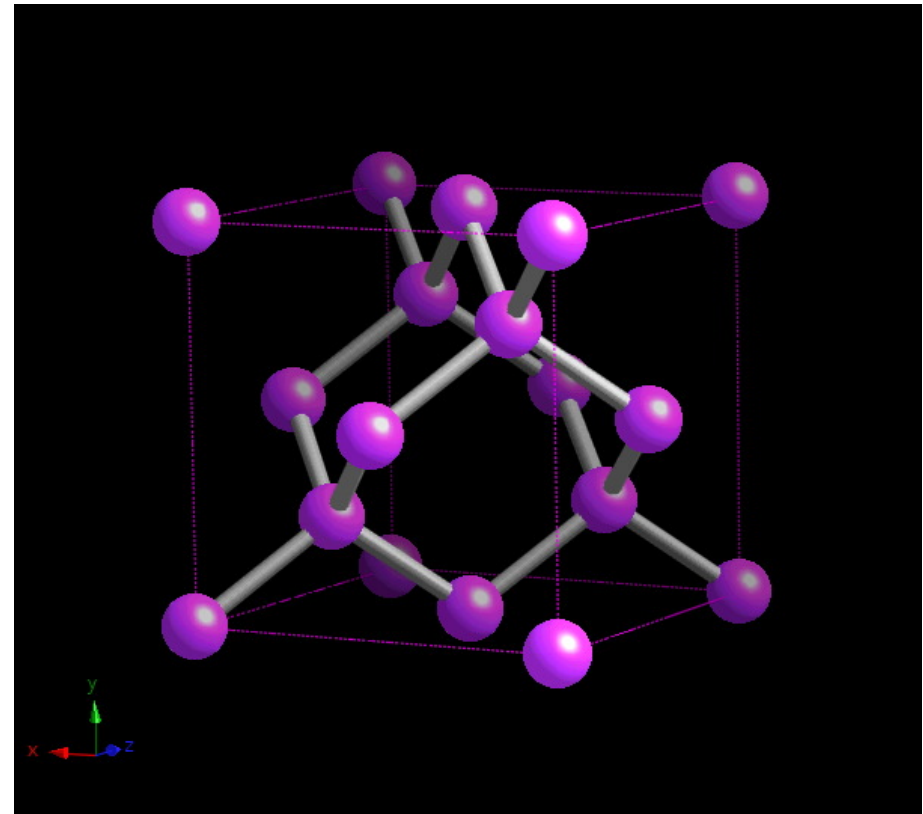
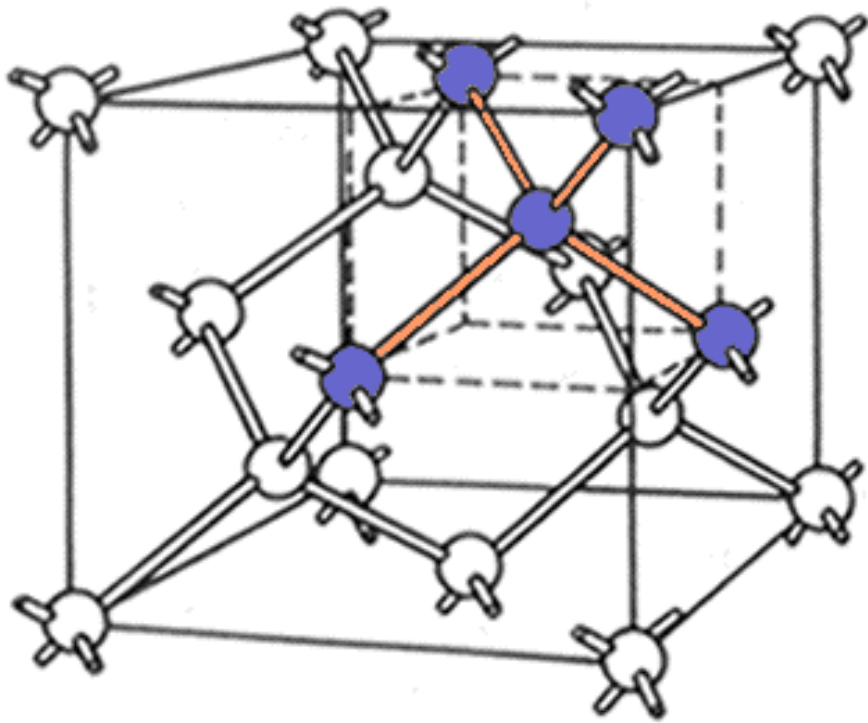
Column IV: *Si, Ge*
basic semiconductors,

III-V compound:
like *Ga-As*

II-VI compounds:
like *Hg-Te, Cd-Te,*

3D-compounds:
Bi_{1-x}Sb_x

The Diamond Lattice



The Diamond Lattice

G. LEMAN, J. FRIEDEL, *J. Appl. Phys.*, **33**, (1962), 281-285

- Projecting $\mathbb{Z}^4$ onto $\mathbb{R}^3$ perpendicular to $f = 1/2(1, 1, 1, 1)$:
each patch $\{m, m + e_1, m + e_2, m + e_3, m + e_4\}$ projects as a

regular tetrahedron

- If $i \in \{0, 1, 2, 3\}$ then

$$\mathcal{E}_i = \left\{ m \in \mathbb{Z}^4 ; \sum_{\alpha=1}^4 m_{\alpha} = i \right\}$$

Then keep only the points in $\mathcal{E}_0 \cup \mathcal{E}_1$

- $m \in \mathcal{E}_0 \Leftrightarrow m + e_{\alpha} \in \mathcal{E}_1$ gives the *staggering* between tetrahedra.

Chemical Bonds

G. LEMAN, J. FRIEDEL, *J. Appl. Phys.*, **33**, (1962), 281-285

- Each atom has *4-valence electrons* in orbitals s, p_x, p_y, p_z with same energy.
- Each such orbital is a *vector* in a Hilbert space $\Rightarrow \mathbb{C}^4$.
- Using the $\mathbb{Z}_4$ Fourier transform gives four linear combinations with the symmetry of the *tetrahedron*. The *electron density* points in space in the four directions of the tetrahedron.
- Each valence state creates a band in the lattice. The spins double their number, thus *8-bands*
- Adding the *$e - e$ interaction* onsite leads to *splitting* of levels $\Rightarrow$ creates a gap between *4-valence* and *4-conduction* bands.

Spin-Orbit Coupling

E. U. CONDON, G. H. SHORTLEY, *The Theory of Atomic Spectra*, Cambridge University Press (1935)

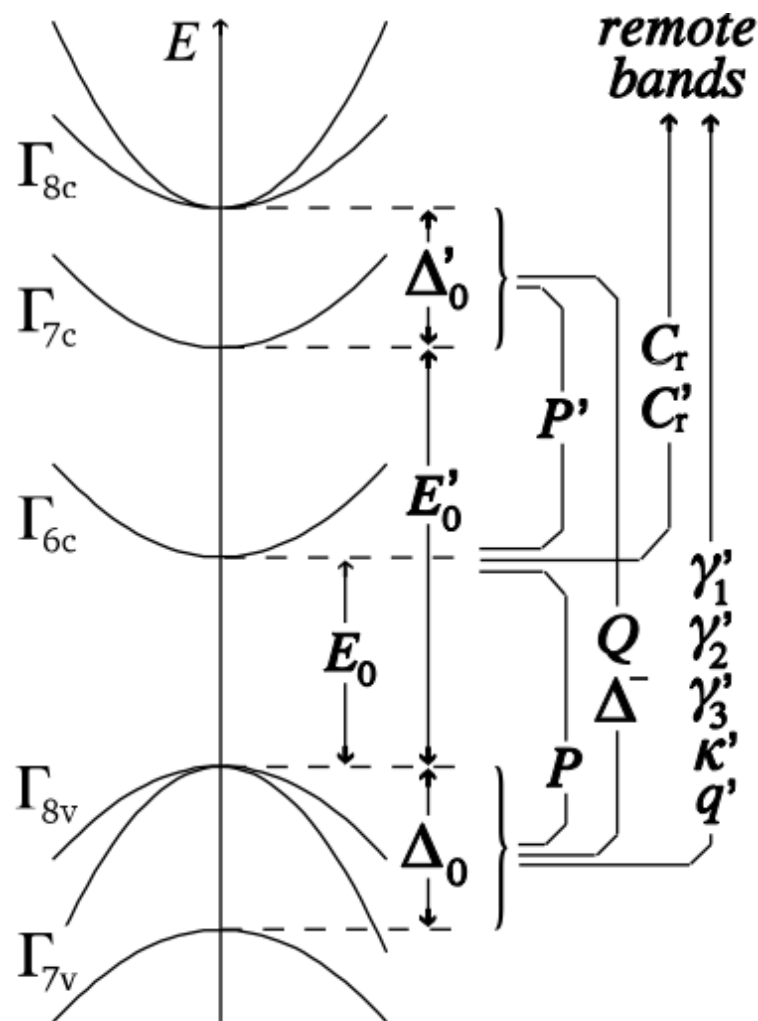
- The electron rotation around a nucleus creates a magnetic field which interact with its own spin (spin-orbit coupling)
- Relativistic corrections gives the spin-orbit energy

$$H_{SO} = \frac{\mu_B}{\hbar m_e c^2} \frac{1}{r} \frac{\partial U(r)}{\partial r} \vec{L} \cdot \vec{S}$$

- $\vec{L}$ is the *angular momentum*, $\vec{S}$ is the *spin*
- $U(r)$ is the radial potential seen by the electron.
- μ_B =Bohr magneton, m_e =electron mass, e =electron charge, c =speed of light.

Spin-Orbit Coupling

R. WINKLER, *Spin-Orbit Coupling Effects in Two-Dimensional Electron and Hole Systems*, Springer, (2003)



If the diamond lattice is shared by two atomic species, the point symmetry between the two sublattices is broken. Then the spin-orbit interaction creates a band splitting

III - THE $\mathbb{Z}_2$ -INVARIANT

M. Z. HAZAN, C. L. KANE, Topological Insulators, *Rev. Mod. Phys.*, **82**, (2010), 3045-3067

M. ATIYAH, I. M. SINGER, Index Theory for Skew-Adjoint Fredholm Operators,
Inst. Hautes Études Sci. Publ. Math., **37**, (1969), 5-26

Real Hilbert Spaces

- A Hilbert space can be seen as a *real Hilbert space* $\mathcal{H}$ equipped with a real linear operator J such that

$$J^{-1} = J^T = -J \qquad \langle f|g \rangle_{\mathbb{C}} = \langle f|g \rangle_{\mathbb{R}} + \imath \langle Jf|g \rangle_{\mathbb{R}}$$

- Then $\mathbb{C}$ acts through $z = x + \imath y \mapsto x + Jy$
- A $\mathbb{C}$ -linear operator A is an $\mathbb{R}$ -linear map such that $AJ = JA$.
- *Complex conjugacy* is given by an $\mathbb{R}$ -linear map C such that $C = C^{-1} = C^T$, $CJ + JC = 0$. Then any $f \in \mathcal{H}$ can be uniquely written as $f = f_0 + Jf_1$ with $Cf_i = f_i$

Time Reversal Symmetry

- For the time dependent *Schrödinger equation* the time-reversal symmetry is given by C:

$$i\hbar \frac{\partial \psi}{\partial t} = -\frac{\hbar^2}{2m} \Delta \psi + V\psi \quad \Rightarrow \quad -i\hbar \frac{\partial \bar{\psi}}{\partial t} = -\frac{\hbar^2}{2m} \Delta \bar{\psi} + V\bar{\psi}$$

- For the relativistic *Dirac equation* the time-reversal symmetry is given by an operator Θ such that $\Theta^2 = -1$. The same occurs for spin-orbit coupling.
- In the real version of Hilbert spaces this gives two $\mathbb{R}$ -linear map J, Θ such that (*Clifford Algebra*)

$$J^{-1} = J^T = -J \quad \Theta^{-1} = \Theta^T = -\Theta \quad \Theta J + J\Theta = 0$$

Kramers Degeneracy

- Let $H = H^*$ be a *time-reversal symmetric* selfadjoint operator. In the real version then H is an $\mathbb{R}$ -linear map on $\mathcal{H}$ commuting with both J, Θ .
- If $f \in \mathcal{H}$ is an *eigenstate* of H , namely $Hf = Ef$, then $H\Theta f = E\Theta f$ is another one.
- However $\langle \Theta f | f \rangle_{\mathbb{C}} = 0$. Since $\|f\| = \|\Theta f\|$, it follows that every eigenvalue is *twice degenerate*.

Momentum Space

- If the Hamiltonian is *periodic* on the diamond lattice, Bloch theory implies that it can be seen as a k -dependent 8×8 -matrix with $k \in \mathbb{B} \simeq \mathbb{T}^3$. Matrix *indices* label the *8-orbitals* close to the Fermi level.
- *Time reversal* symmetry implies

$$\Theta H(k) \Theta^{-1} = H(-k)$$

- Let Λ be the set of points in the Brillouin zone such that $k = -k$.
- At each point $k \in \Lambda$, the matrix $H(k)$ commutes with Θ and its eigenstates are *Kramers-degenerate*.

The $\mathbb{Z}_2$ -index

- Each *occupied band*, labelled by m , is given by a Bloch function $u_m(k)$ with values in the Hilbert space $\mathcal{H}$. Let

$$W_{m,n}(k) = \langle u_m(k) | \Theta u_n(-k) \rangle$$

- $W(k)$ is unitary and $W^T(k) = -W(-k)$. In particular it is *antisymmetric* at points of Λ .

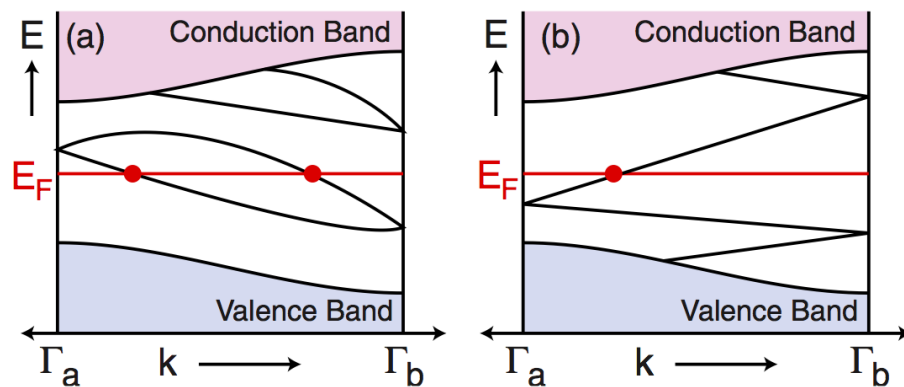
(Smoothness is required ! The $u_m(k)$ must be time-reversal "compatible" !)

- Then the $\mathbb{Z}_2$ -index $\nu \in \mathbb{Z}_2$ is defined by

$$(-1)^\nu \stackrel{\text{def}}{=} \prod_{k \in \Lambda} \frac{\text{Pf}[W(k)]}{\sqrt{\det(W(k))}}$$

Edge States

- In experiments, a *spin-polarized current* is protected on the *edges* of the quantum well. This edge is $1D$.
- Truncated space along the edge leads to new *eigenstates in the Fermi gap*. The corresponding eigenfunction are *localized* on the edges. If the edge is a straight line, the periodicity along the edge allows to use Bloch theory with $k \in \mathbb{T}$.



Edge states are doubly degenerate on Λ .
The parity of the number of states with energy E_F is given by ν

Disordered Case: Numerical Results

E. PRODAN, B. LEUNG, *Phys. Rev. B*, **85**, 205136, (2012)

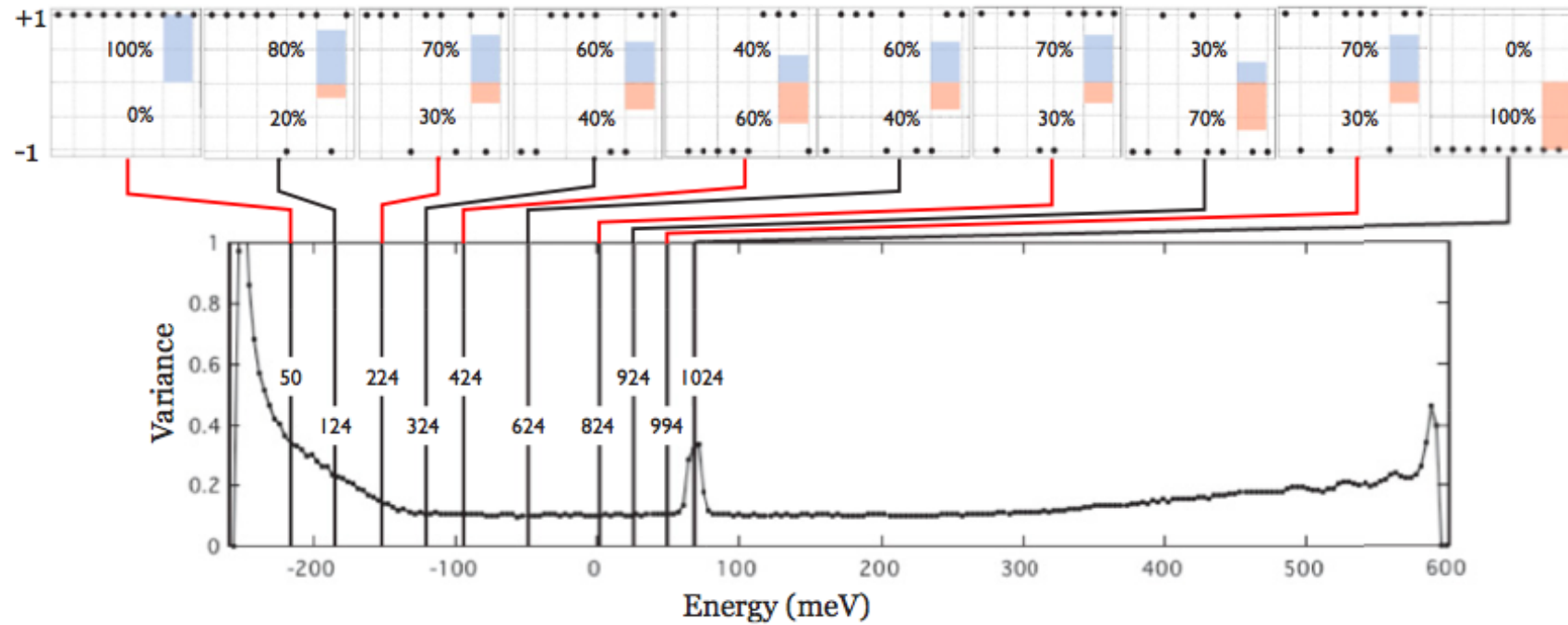


FIG. 5. (Color online) The upper panels show the $\mathbb{Z}_2$ invariant computed along the path (1) of Fig. 4 on an $8 \times 8 \times 8$ unit-cell lattice via twisted boundary conditions. The dimension of the occupied space was slowly reduced from 1024 to 124, as indicated in the figure. For each $\mathbb{Z}_2$, the calculation was repeated for 10 random disorder configurations and the output is shown by the full dots, exactly how it occurs in the actual calculation. The percentages of the $\mathbb{Z}_2 = \pm 1$ occurrences are displayed in each panel. The lower panel shows the variance of the level spacings for $W = 300$ meV, and the averaged Fermi levels (see the vertical lines) corresponding to each $\mathbb{Z}_2$ calculation.

Open Problems

- Is the definition of ν amenable to an index theory valid also for *disordered systems* ?
- Atiyah-Singer developed a $\mathbb{Z}_2$ -index theory for *antisymmetric Fredholm* operators. Is ν equal to such an index ?

IV - MAGNETO-ELECTRIC RESPONSE

Main References

Periodic Case:

R. D. KING-SMITH, D. VANDERBILT, *Phys. Rev. B*, **47**, (1993), 1651-1654

X. L. QI, T. L. HUGHES, S. C. ZHANG, *Phys. Rev. B*, **78**, (2008), 195424

A. M. ESSIN, J. E. MOORE, D. VANDERBILT, *Phys. Rev. Lett.*, **102**, (2009), 146805

A. M. ESSIN, A. M. TURNER, J. E. MOORE, D. VANDERBILT, *Phys. Rev. B*, **81**, (2010), 205104

A. MALASHEVICH, I. SOUZA, S. COH, D. VANDERBILT, *New J. Phys.*, **12**, (2010), 053032

Disordered Case:

B. LEUNG, E. PRODAN, *J. Phys. A: Math. and Theor.*, **46**, (2013), 085205

H. SCHULZ-BALDES, S. TEUFEL, *Comm. Math. Phys.*, **319**, (2013), 649-681

E. PRODAN, B. LEUNG, J. BELLISSARD, "The non-commutative n th-Chern number ($n \geq 1$)", (*in preparation*), (2013)

Magneto-Electric Response Coefficient

- The *magnetization* $\vec{M}$ induced by the electronic *orbital* motion induced by a small *electric field* $\vec{E}$ is given to lowest order by the response coefficient at zero magnetic field $\vec{B}$

$$\alpha_{ij} = \left. \frac{\partial M_j}{\partial E_i} \right|_{\vec{B}=0}$$

- Equivalently the electric *polarization* $\vec{P}$ of the orbital motion induced by a small *magnetic field* is also given by the same coefficient

$$\alpha_{ij} = \left. \frac{\partial P_i}{\partial B_j} \right|_{\vec{E}=0}$$

Magneto-Electric Response Coefficient

- For a periodic 3D-insulator, with Bloch functions $u_m(k)$ representing the *occupied bands* let $\mathcal{A}_j^{mn}$ be the *Berry connection* defined by

$$\mathcal{A}_j^{mn}(k) = \left\langle u_m(k) \left| \frac{\partial}{\partial k_j} \right| u_n(k) \right\rangle$$

- *Then the tracial part is given by* (Qi, Hughes, Zhang '06)

$$\theta \stackrel{\text{def}}{=} \frac{1}{3} \sum_{i=1}^3 \alpha_{ii} = \frac{1}{2\pi} \int_{\mathbb{B}} d^3k \, \epsilon^{ijl} \, \text{Tr} \left[\mathcal{A}_i \partial_j \mathcal{A}_l - \frac{2i}{3} \mathcal{A}_i \mathcal{A}_j \mathcal{A}_l \right]$$

- The *r.h.s.* is a topological invariant called the *Chern-Simons action*.

Polarization

- There is a problem in *defining unambiguously* the electric polarization of a solid.
- However the *change* of the polarization under an adiabatic evolution can be defined through *perturbation theory* (King-Smith & Vanderbilt '93). (Ex.: piezoelectric, magnetoelectric response)
- The *adiabatic* variation of the polarization is given by

$$\frac{\partial \vec{P}}{\partial \lambda} = \mathcal{T}_{\mathbb{P}} [\rho(\lambda) \vec{J}(\lambda)] \quad \vec{J}(\lambda) = i [H(\lambda), \vec{X}] \quad (\text{charge current})$$

where $\rho(\lambda)$ is the adiabatic evolution of the *density matrix* defining the quantum state of the system.

Polarization

- Let $\lambda \in [0, 1] \mapsto H(\lambda)$ be a *smooth* adiabatic evolution of the Hamiltonian. It will be assumed that a *spectral gap persists* along the way at the Fermi level and that $\rho(\lambda = 0) = P_F$.
- The adiabatic evolution is driven by

$$i\epsilon \frac{\partial \rho}{\partial \lambda} = [H(\lambda), \rho(\lambda)] \quad \epsilon \downarrow 0$$

- Then *(King-Smith & Vanderbilt '83, Schulz-Baldes & Teufel '13)*

$$\Delta \vec{P} = \int_0^1 d\lambda \frac{\partial \vec{P}}{\partial \lambda} = \int_0^1 d\lambda \mathcal{T}_{\mathbb{P}} \left(P_F(\lambda) \left[\partial_\lambda P_F(\lambda), \vec{\nabla} P_F(\lambda) \right] \right) + O(\epsilon^\infty)$$

Magnetization

- A similar formula can be established for the $3D$ -magnetization $\vec{M}$ at zero temperature (*Schulz-Baldes & Teufel '13*)

$$M_i = \frac{i \epsilon^{ijk}}{2} \mathcal{T}_{\mathbb{P}} \left(|E_F - H| \left[\partial_j P_F, \partial_k P_F \right] \right)$$

- The previous formula holds also if the *Fermi level* belongs to a *mobility gap*, namely if $P_F \in \mathcal{S}$ is Sobolev (*Schulz-Baldes & Teufel '13*).

Magneto-Electric Response Coefficient

- Differentiating the polarization *w.r.t.* to the magnetic field can be done using a *Itô derivative* δ_B acting on the observable algebra

(JB '88)

- It gives (Leung & Prodan '13)

$$\theta = \frac{1}{2} \int_0^1 d\lambda \mathcal{T}_{\mathbb{P}} (P_F dP_F dP_F dP_F dP_F) + \frac{1}{3} \mathcal{T}_{\mathbb{P}} ((1 - 2P_F) dP_F \delta_B P_F) \Big|_{\lambda=0}^{\lambda=1}$$

- Here λ is introduced as a *fourth dimension* and then

$$df = \partial_{\lambda} f d\lambda + \sum_{i=1}^3 \partial_i f dk_i$$

Magneto-Electric Response Coefficient

- If γ is *adiabatic smooth paths* in the the Hamiltonian space, let $\Theta\gamma$ be the path obtained in the Hamiltonian space by *time-reversal symmetry*. Then $\gamma - \Theta\gamma$ is a *loop* in the Hamiltonian space.
- The magneto-electric response is then given by *(Qi, Hughes, Zhang '06, Leung & Prodan '13)*

$$\Delta\theta(\gamma - \Theta\gamma) = \frac{1}{2} \oint_{\gamma - \Theta\gamma} d\lambda \mathcal{T}_{\mathbb{P}}(P_F dP_F dP_F dP_F dP_F) = \frac{1}{2} \mathbf{Ch}_2(P_F)$$

- This formula is still valid provided P_F belongs to the Sobolev space $\mathcal{W}^{2,4}(\mathcal{A}, \mathcal{T}_{\mathbb{P}})$ *(Leung, Prodan, JB '13)*

$$\mathcal{W}^{2,4}(\mathcal{A}, \mathcal{T}_{\mathbb{P}}) = \left\{ A \in \mathcal{A}; \mathcal{T}_{\mathbb{P}}(|A|^2) + (|\vec{\nabla} A|^4)^{1/2} < \infty \right\}$$

Sobolev Norm & Localization

- The expression

$$\ell_4(E_F) = \left(|\vec{\nabla} P_F|^4 \right)^{1/4}$$

has the dimension of a *length* and can be seen as a milder version of the *localization length* at the Fermi level.

- **Theorem** *In the case of strong enough independent disorder at each lattice site, the Aizenman-Molčanov technique apply to prove that $\ell_4(E_F)$ is finite so that $P_F \in \mathcal{W}^{2,4}$*

Conclusion

- *the second Chern number $\mathbf{Ch}_2(P_F)$ is an integer. (Connes '83)*
- *The magneto-electric response $\Delta\theta(\gamma - \Theta\gamma)$ at zero magnetic field along an adiabatic loop of the Hamiltonian, is quantized and is given by half the second Chern number of the Fermi projection.*
- *$\Delta\theta(\gamma - \Theta\gamma)$ is either an integer or half an integer; both character survive in the limit of zero magnetic field, namely for topological insulators with non trivial $\mathbb{Z}_2$ invariant there are loops for which $\Delta\theta(\gamma - \Theta\gamma)$ is half an integer.*
- *This quantization survives if the solid is disordered whenever the Fermi level belongs to a mobility gap.*

Thanks for listening !